NSN 5962-01-210-1826



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-210-1826 **Body Length:** Between 0.890 inches and 0.930 inches **Body Width:** Between 0.280 inches and 0.310 inches **Body Height:** Between 0.080 inches and 0.120 inches **Operating Tempurature Range:** -55.0 to 125.0 degrees celsius **Storage Tempurature Range:** -65.0 to 150.0 degrees celsius **End Application:** 5805-01-032-1694 switchboard, tel **Features Provided:** Programmable and hermetically sealed and monolithic and schottky **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 125.00 nanoseconds propagation delay time, low to high level output and 125.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 18 printed circuit Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig: A458a0